

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,891,188 B2
APPLICATION NO. : 10/717374
DATED : May 10, 2005
INVENTOR(S) : Mears et al.

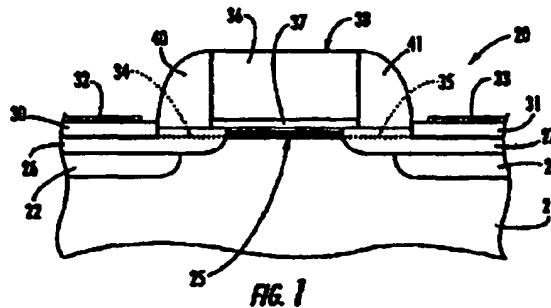
Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In the Drawings

Delete: FIG. 1

Insert: New FIG. 1



Column 1, Line 42

Delete: "on a binary"

Insert: --on binary--

Column 1, Line 66

Delete: "in a silicon"

Insert: --in silicon--

Column 1, Line 67

Delete: "electromuminescence"

Insert: --electroluminescence--

Column 3, Line 4

Delete "as may"

Insert: --as may be--

Column 5, Line 11

Delete: "gate 35"

Insert: --gate 38--

Column 5, Line 60

Delete: "gate 35"

Insert: --gate 38--

Column 7, Line 63

Delete: "from the both"

Insert: --from both--

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It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 9, Lines 44-46 Delete: "In other processes and devices the structures of the present invention may be formed on a portion of a wafer or across substantially all of a wafer."

Column 9, Line 59 Delete: "also formed"
Insert: --also be formed--

This certificate supersedes Certificate of Correction issued September 26, 2006.

Signed and Sealed this

Twenty-first Day of November, 2006

A handwritten signature in black ink, appearing to read "Jon W. Dudas". The signature is stylized with a large, looped initial "J" and a distinct "D".

JON W. DUDAS
Director of the United States Patent and Trademark Office